



Additional Information







Resources Accessories

Samples

Agency Approvals

Agency	Agency File Number
<i>71</i> .	E230531

Maximum Ratings and Thermal Characteristics

(T_A=25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit	
Peak Pulse Power Dissipation at	8/20µs (Note 2)	D	1200	W
$T_A = 25^{\circ}C$ (Note 1)	10/1000µs (Note 3)	P _{PPM}	200	W
Thermal Resistance	$R_{\theta JA}$	220	°C/W	
Thermal Resistance	$R_{\theta JL}$	100	°C/W	
Operating Tempera	T	-55 to 150	°C	
Storage Temperatur	T _{STG}	-55 to 150	°C	

Notes:

1. Non-repetitive current pulse, per Fig. 4 and derated above T_J (initial) =25°C per Fig. 3.

Description

SMF3.3 is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Features and Benefits

- 200W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycle): 0.01%
- 1200W peak pulse power capability at 8/20us waveform
- Excellent clamping capability
- Compatible with industrial standard package SOD-123FL
- Low profile: maximum height of 1.08mm.
- For surface mounted applications to optimize board space
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC 61000-4-2 ESD 30kV(Air), 30kV (Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2

- EFT protection of data lines in accordance with IEC 61000-4-4
- Fast response time: typically less than 1.0ns from 0 Volts to VBR min
- High temperature soldering: 260°C/30 seconds at terminals
- Built-in strain relief
- Meet MSL level1, per J-STD-020C, LF maximun peak of 260°C
- Matte tin lead–free plated
- Halogen-free and RoHScompliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

Applications

SMF3.3 series is ideal for the protection of portable electronics/ hard drives, notebooks, VCC busses, POS terminal, SSDs, power supplies, monitors, and vulnerable circuit used in other consumer applications.

Functional Diagram



Electrical Characteristics (T_A=25°C unless otherwise noted)

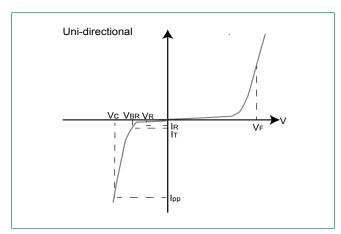
Part Number		Breakdown Voltage V _{BR} ((Volts) @ I _T		Test Current I _T	Reverse	Maximum Reverse Leakage @ V _R	Maximum Peak Pulse Current (10/1000µS)	Maximum Clamping Voltage @I _{pp} (10/1000uS)	Maximum Peak Pulse Current (8/20uS)	Maximum Clamping Voltage @I _{pp} (8/20uS)
		MIN	MAX	(mA)	(V)	I _R (μA)	I _{pp} (A)	V _c (V)	I _{pp} (A)	V _c (V)
SMF3.3	33	3.4	4.3	10	3.3	0.5	30.0	6.8	120.0	10.0

Notes

- 1. V_{BR} measured after I_{T} applied for 300 μ s, I_{T} = sequare wave pulse or equivalent.
- 2. Surge current waveform per 10/1000µs exponential wave and derated per Fig.2.
- 3. All terms and symbols are consistent with ANSI/IEEE C62.35.
- 4. Surge current waveform per 8/20µs exponential wave and derated per Fig.6



I-V Curve Characteristics



- $\mathbf{P}_{_{\mathbf{PPM}}}$ **Peak Pulse Power Dissipation** Max power dissipation
- V_a Stand-off Voltage -- Maximum voltage that can be applied to the TVS without operation
- $V_{\tt BR}$ Breakdown Voltage Maximum voltage that flows though the TVS at a specified test current (IT)
- I_s Reverse Leakage Current Current measured at VR
- V_F Forward Voltage Drop for Uni-directional

Note: VF distribution range from 7V to 16V at IF 1mA.

Ratings and Characteristic Curves (T_A=25°C unless otherwise noted)

Figure 1 -TVS Transients Clamping Waveform

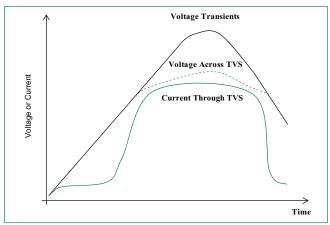


Figure 2 -Peak Pulse Power Rating Curve

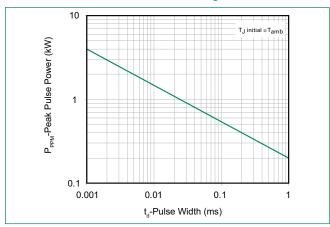


Figure 3 -Peak Pulse Power Derating Curve

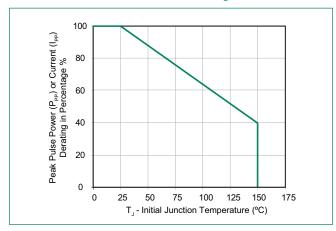


Figure 4 - 10/1000µS Pulse Waveform

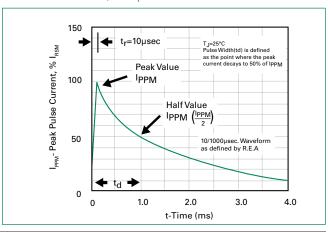




Figure 5 - Capacitance vs. Reverse Bias

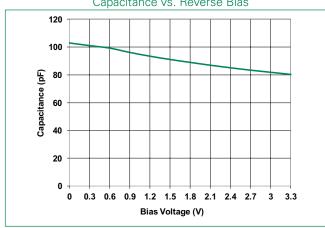
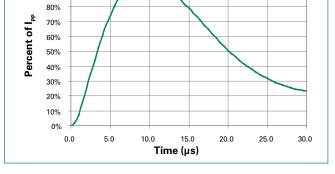


Figure 6 -8/20µS Pulse Waveform

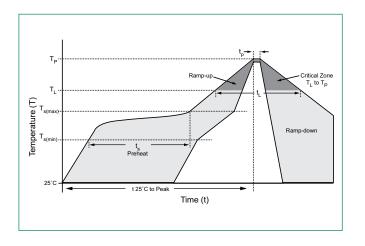
110% 100%

90%



Soldering Parameters

Reflow Cond	lition	Lead-free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 - 120 secs	
Average ram peak	p up rate (Liquidus Temp (T _L) to	3°C/second max	
T _{S(max)} to T _L -	Ramp-up Rate	3°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nellow	-Time (min to max) (t _L)	60 – 150 seconds	
Peak Temper	ature (T _P)	260+0/-5 °C	
Time within	5°C of actual peak Temperature (t _p)	30 seconds max	
Ramp-down	Rate	6°C/second max	
Time 25°C to	peak Temperature (T _P)	8 minutes max.	
Do not excee	ed	260°C	



Physical Specifications

Case	SOD-123FL plastic over passivated junction
Polarity	Color band denotes cathode except bipolar
Terminal	Matte tin-plated leads, solderable per JESD22-B102

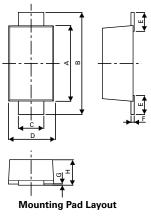
Environmental Specification

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, LEVEL 1
H3TRB	JESD22-A101
RSH	JESD22-A111



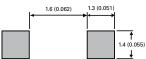
Inches

Dimensions - SOD-123FL Package

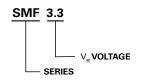


Dimensions					
Dimensions	Min	Max	Min	Max	
А	2.70	3.10	0.106	0.122	
В	3.50	3.90	0.138	0.154	
С	0.85	1.05	0.033	0.041	
D	1.70	2.00	0.067	0.079	
E	0.43	0.83	0.017	0.033	
F	0.10	0.25	0.004	0.010	
G	0.00	0.10	0.000	0.004	
Н	0.90	1.08	0.035	0.043	

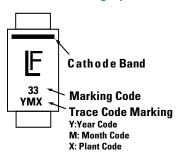
Millimeters



Part Numbering System

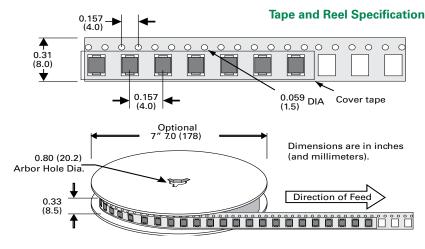


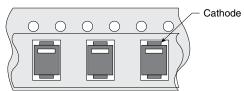
Part Marking System



Packaging Options

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
SMF3.3	SOD-123FL	3000	Tape & Reel – 8mm tape/7" reel	EIA RS-481





Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at http://www.littelfuse.com/disclaimer-electronics.

